

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C (Note 6)
-40V	25mΩ @ V _{GS} = -10V	-8.6A
	45mΩ @ V _{GS} = -4.5V	-7.0A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Motor control
- Backlighting
- DC-DC converters
- Printer equipment

Features

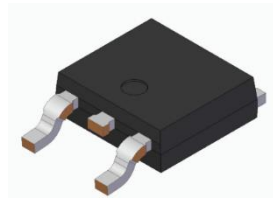
- Low On-Resistance
- Fast Switching Speed
- Low Input/Output Leakage
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The DMP4025LK3Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

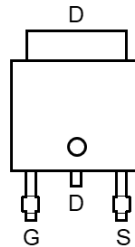
Mechanical Data

- Package: TO252
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram Below
- Terminals: Finish - Matte Tin Annealed over Copper Lead Frame. Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 0.315 grams (Approximate)

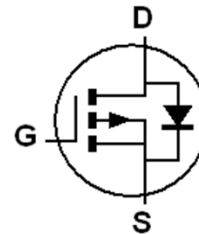
TO252 (DPAK)



Top View



Top View
Pinout



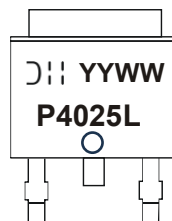
Device Symbol

Ordering Information (Note 4)

Orderable Part Number	Package	Packing	
		Qty.	Carrier
DMP4025LK3Q-13	TO252 (DPAK)	2,500	Tape & Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



J11 = Manufacturer's Marking
 P4025L = Product Type Marking Code
 YYWW = Date Code Marking
 YY = Year (ex: 26 = 2026)
 WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

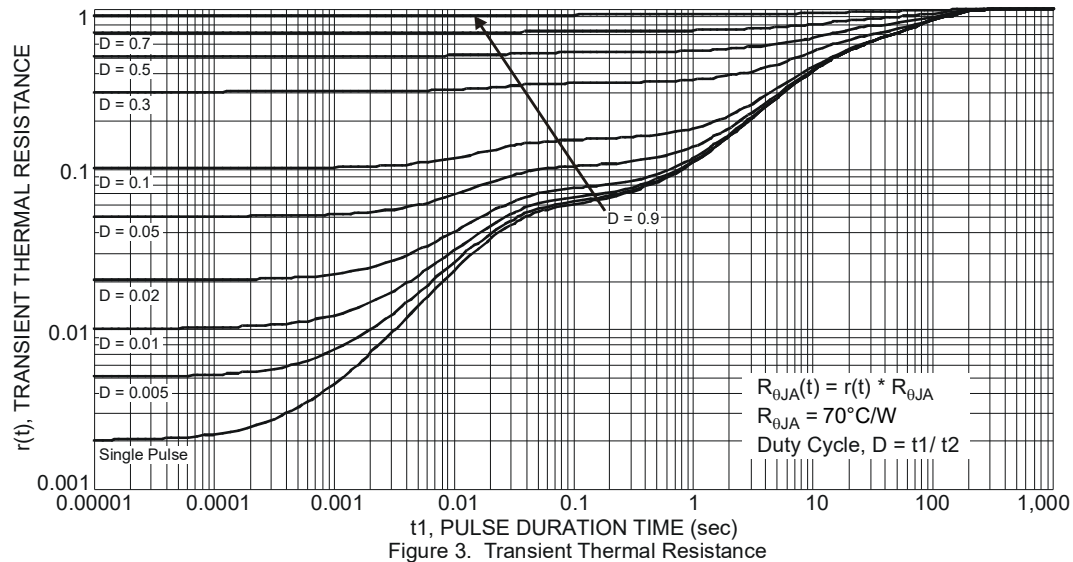
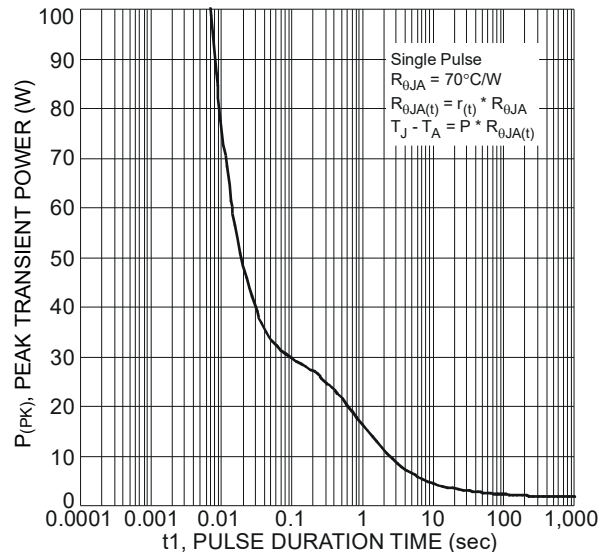
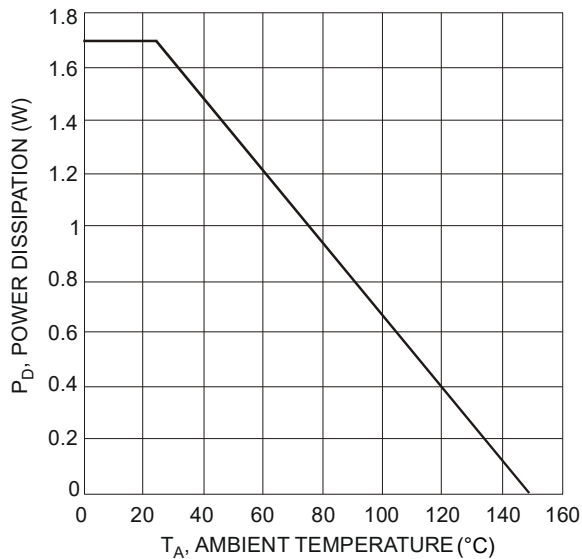
Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	-40	V
Gate-Source Voltage			V _{GSS}	±20	
Continuous Drain Current	V _{GS} = -10V	(Note 6)	I _D	-8.6	A
		T _A = +70°C (Note 6)		-6.9	
		(Note 5)		-6.7	
Pulsed Drain Current	V _{GS} = -10V	(Note 7)	I _{DM}	-40	
Continuous Source Current (Body Diode)		(Note 7)	I _S	-8.6	
Pulsed Source Current (Body Diode)		(Note 7)	I _{SM}	-40	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P _D	1.7	W
	(Note 6)		2.78	
Thermal Resistance, Junction to Ambient	(Note 5)	R _{θJA}	74	°C/W
	(Note 6)		45	
Thermal Resistance, Junction to Case	(Note 6)	R _{θJC}	7.1	
Thermal Resistance, Junction to Lead	(Note 8)	R _{θJL}	1.43	
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

- Notes:
5. For a device surface mounted on minimum recommended FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
 6. Same as note (5), except the device is surface mounted on 25mm X 25mm X 1.6mm FR4 PCB.
 7. Repetitive rating on 25mm X 25mm FR4 PCB, D=0.02, pulse width 300μs – pulse width by maximum junction temperature.
 8. Thermal resistance from junction to solder-point (at the end of the drain lead).

Thermal Characteristics



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	-40	—	—	V	I _D = -250μA, V _{GS} = 0
Zero Gate Voltage Drain Current	I _{DSS}	—	—	-1	μA	V _{DS} = -40V, V _{GS} = 0
Gate-Source Leakage	I _{GSS}	—	—	±100	nA	V _{GS} = ±20V, V _{DS} = 0
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	-0.8	-1.3	-1.8	V	I _D = -250μA, V _{DS} = V _{GS}
Static Drain-Source On-Resistance (Note 9)	R _{DS(ON)}	—	18	25	mΩ	V _{GS} = -10V, I _D = -3A
			30	45		V _{GS} = -4.5V, I _D = -3A
Forward Transconductance (Notes 9 & 10)	g _{fs}	—	16.6	—	S	V _{DS} = -5V, I _D = -3A
Diode Forward Voltage (Note 9)	V _{SD}	—	-0.7	-1	V	I _S = -1A, V _{GS} = 0
DYNAMIC CHARACTERISTICS (Note 10)						
Input Capacitance	C _{iss}	—	1643	—	pF	V _{DS} = -20V, V _{GS} = 0 f = 1MHz
Output Capacitance	C _{oss}	—	179	—		
Reverse Transfer Capacitance	C _{rss}	—	128	—		
Gate Resistance	R _g	—	6.43	—	Ω	V _{DS} = 0, V _{GS} = 0, f = 1MHz
Total Gate Charge (Note 11)	Q _g	—	14	—	nC	V _{GS} = -4.5V V _{DS} = -20V I _D = -3A
Total Gate Charge (Note 11)	Q _g	—	33.7	—		
Gate-Source Charge (Note 11)	Q _{gs}	—	5.5	—		
Gate-Drain Charge (Note 11)	Q _{gd}	—	7.3	—		
Turn-On Delay Time (Note 11)	t _{D(ON)}	—	6.9	—	ns	V _{DD} = -20V, V _{GS} = -10V I _D = -3A
Turn-On Rise Time (Note 11)	t _R	—	14.7	—		
Turn-Off Delay Time (Note 11)	t _{D(OFF)}	—	53.7	—		
Turn-Off Fall Time (Note 11)	t _F	—	30.9	—		

Notes: 9. Measured under pulsed conditions. Pulse width ≤ 300μs; duty cycle ≤ 2%.
10. For design aid only, not subject to production testing.
11. Switching characteristics are independent of operating junction temperatures.

Typical Characteristics

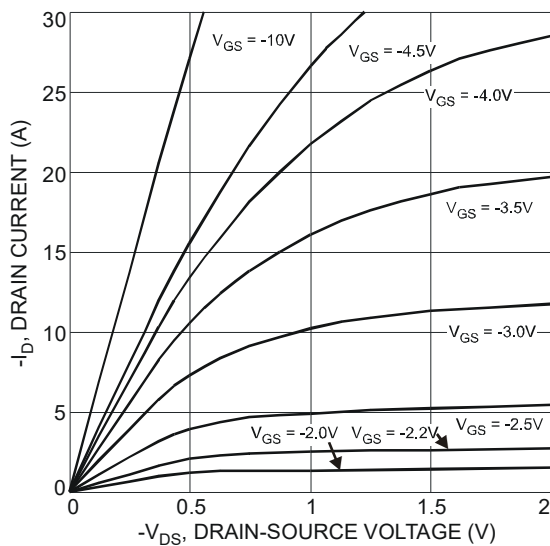


Figure 4. Typical Output Characteristic

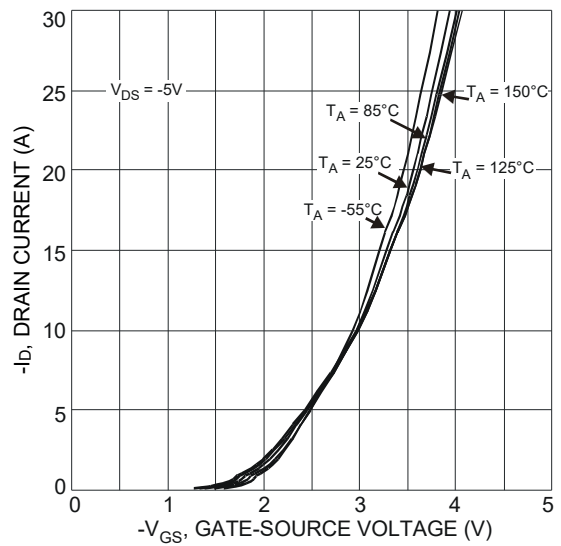


Figure 5. Typical Transfer Characteristic

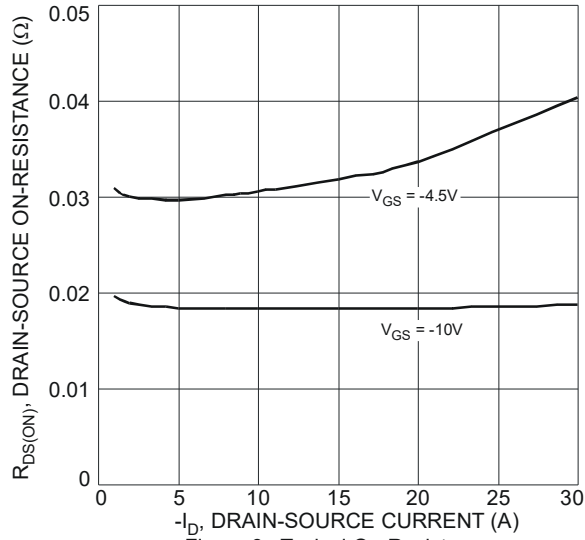


Figure 6. Typical On-Resistance vs. Drain Current and Gate Voltage

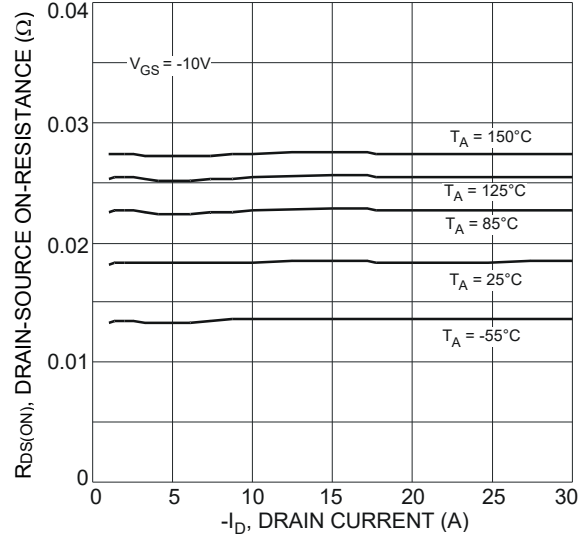


Figure 7. Typical On-Resistance vs. Drain Current and Temperature

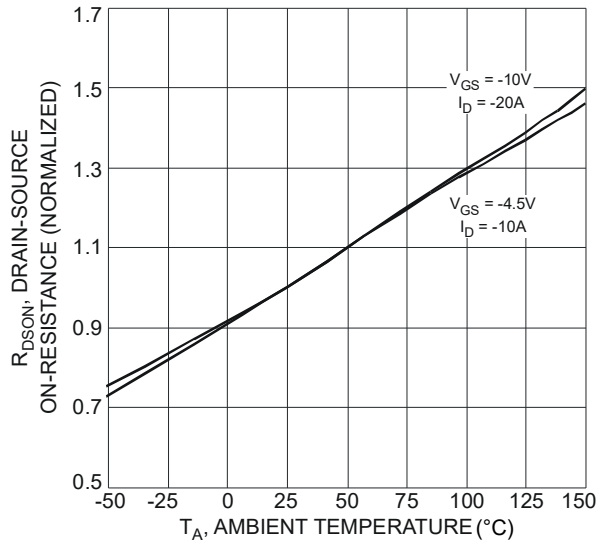


Figure 8. On-Resistance Variation with Temperature

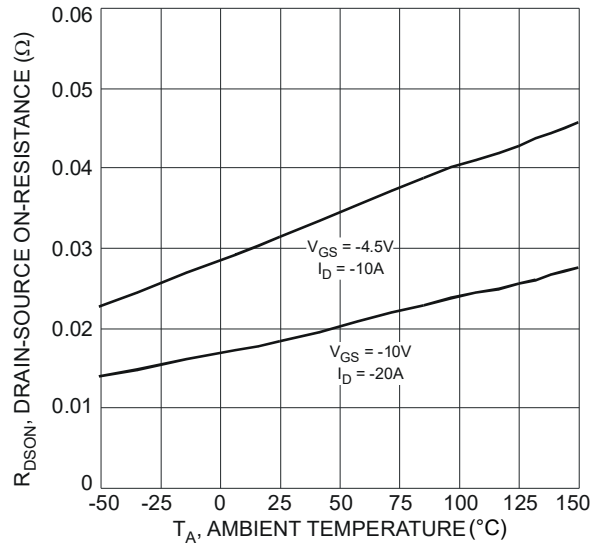


Figure 9. On-Resistance Variation with Temperature

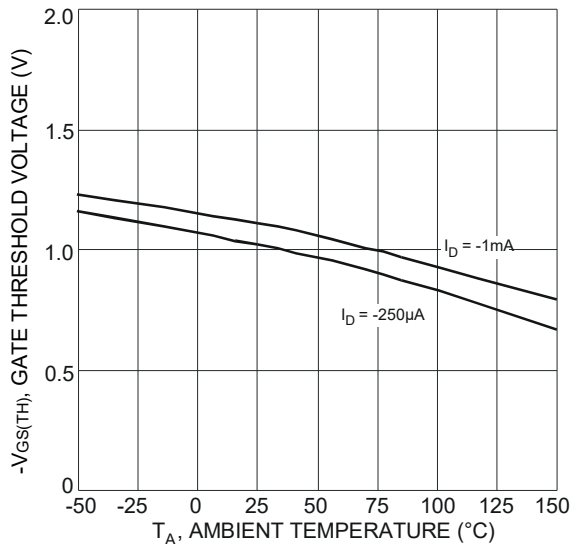


Figure 10. Gate Threshold Variation vs. Ambient Temperature

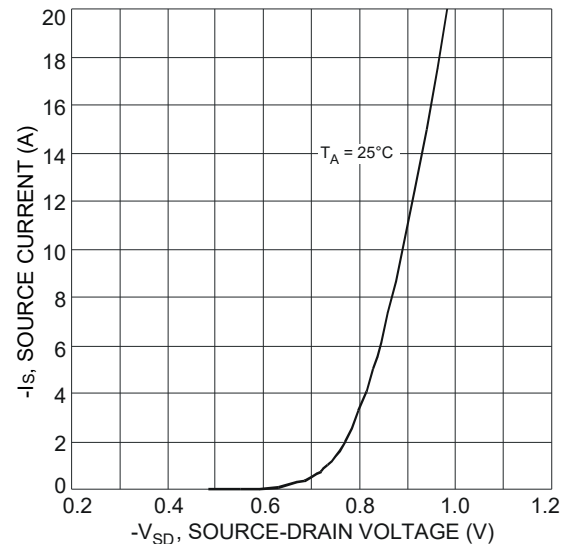
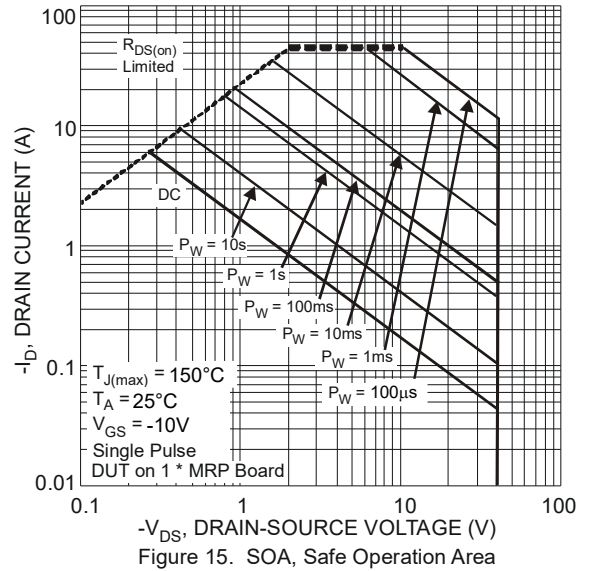
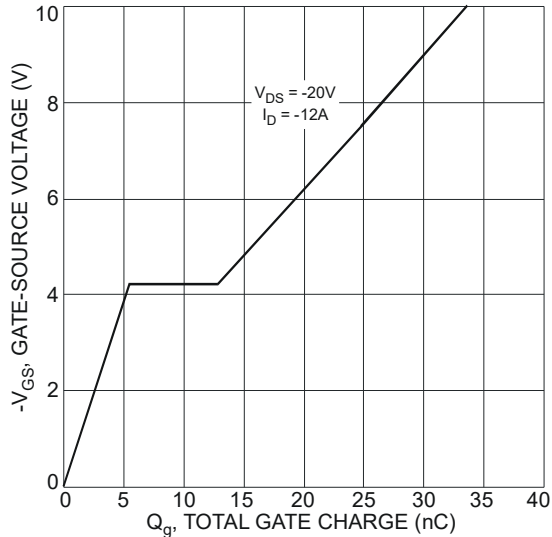
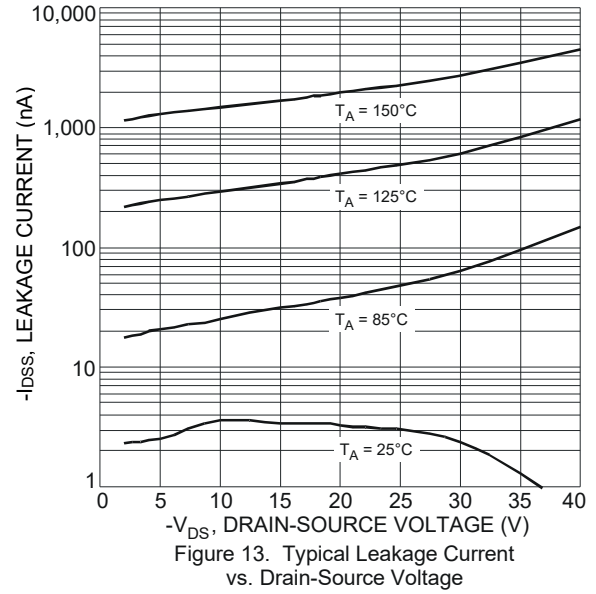
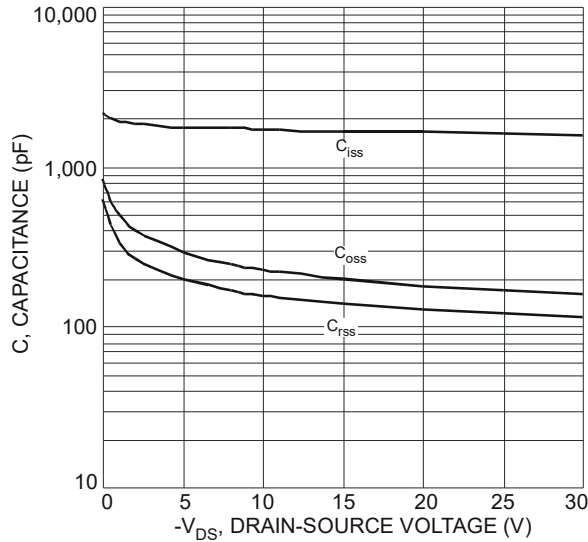


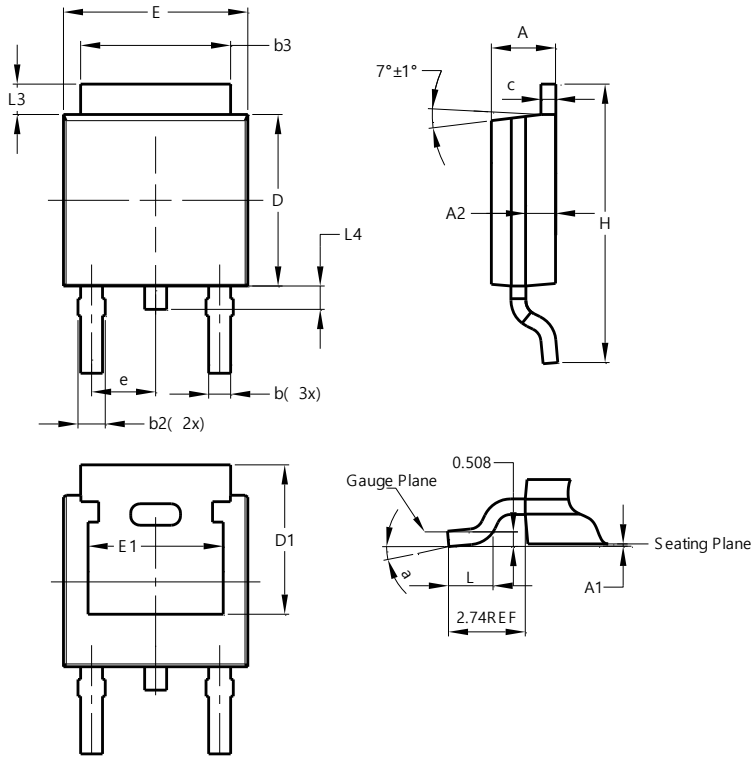
Figure 11. Diode Forward Voltage vs. Current



Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

TO252 (DPAK)

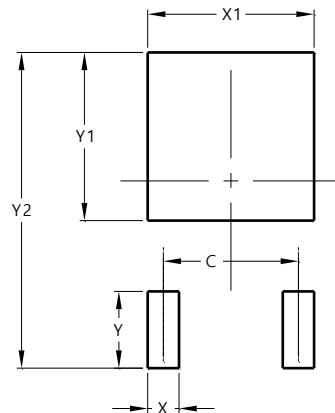


TO252 (DPAK)			
Dim	Min	Max	Typ
A	2.19	2.39	2.29
A1	0.00	0.13	0.08
A2	0.97	1.17	1.07
b	0.64	0.88	0.783
b2	0.76	1.14	0.95
b3	5.21	5.50	5.33
c	0.45	0.58	0.531
D	6.00	6.20	6.10
D1	5.21	--	--
e	2.286 BSC		
E	6.45	6.70	6.58
E1	4.32	--	--
H	9.40	10.41	9.91
L	1.40	1.78	1.59
L3	0.88	1.27	1.08
L4	0.64	1.02	0.83
a	0°	10°	--
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

TO252 (DPAK)



Dimensions	Value (in mm)
C	4.572
X	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700

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